



# PJQ5474A

100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

18A

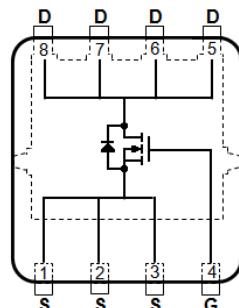
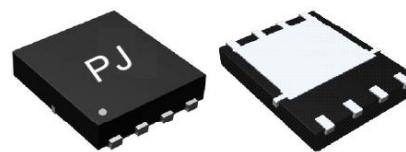
## Features

- RDS(ON) , VGS@10V, ID@18A<50mΩ
- RDS(ON) , VGS@4.5V, ID@15A<55mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

## Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams
- Marking: Q5474A

DFN5060-8L



## Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	18	A
Pulsed Drain Current	$I_{DM}$	36	A
Single Pulse Avalanche Energy <sup>(Note 5)</sup>	$E_{AS}$	16.2	mJ
Power Dissipation	$T_C=25^\circ\text{C}$	52	W
	Derate above $25^\circ\text{C}$	416	$\text{mW}/^\circ\text{C}$
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal resistance - Junction to Ambient, $t < 10\text{s}$ <sup>(Note 3)</sup>	$R_{\theta JC}$	2.4	$^\circ\text{C}/\text{W}$



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## Electrical Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	100	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.5	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=18A$	-	37	50	$m\Omega$
		$V_{GS}=4.5V, I_D=15A$	-	38	55	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=80V, V_{GS}=0V$	-	0.03	1.0	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	$nA$
<b>Dynamic</b> <small>(Note 7)</small>						
Total Gate Charge	$Q_g$	$V_{DS}=80V, I_D=18A,$ $V_{GS}=10V$ <small>(Note 1,2)</small>	-	61	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	8.8	-	
Gate-Drain Charge	$Q_{gd}$		-	11	-	
Input Capacitance	$C_{iss}$	$V_{DS}=15V, V_{GS}=0V,$ $f=1.0MHz$	-	3555	-	$pF$
Output Capacitance	$C_{oss}$		-	119	-	
Reverse Transfer Capacitance	$C_{rss}$		-	56	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=50V, I_D=18A,$ $V_{GS}=10V,$ $R_G=3.3\Omega$ <small>(Note 1,2)</small>	-	16	-	$ns$
Turn-On Rise Time	$t_r$		-	50	-	
Turn-Off Delay Time	$t_{d(off)}$		-	64	-	
Turn-Off Fall Time	$t_f$		-	18	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	18	A
Diode Forward Voltage	$V_{SD}$	$I_S=1.0A, V_{GS}=0V$	-	0.7	1.2	V

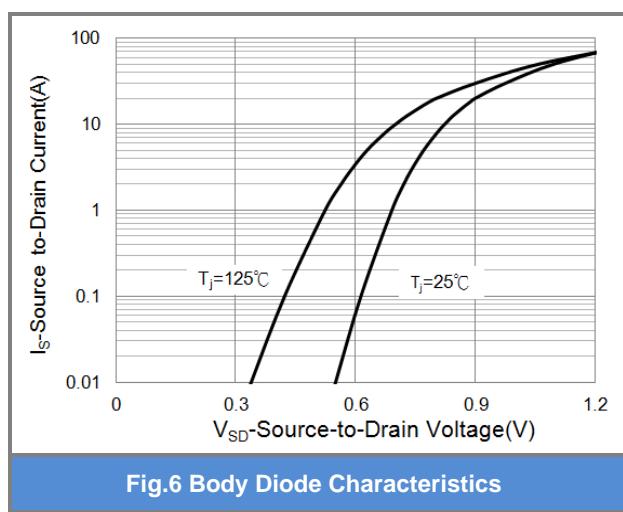
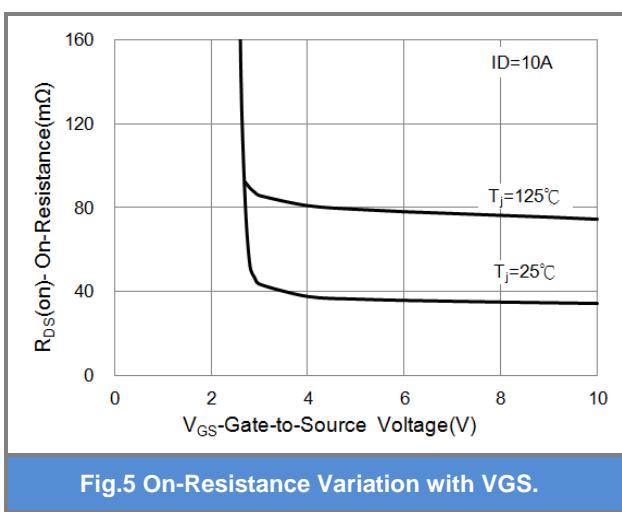
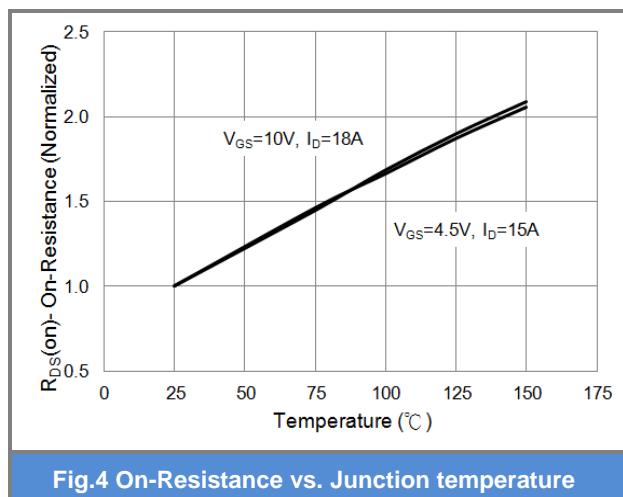
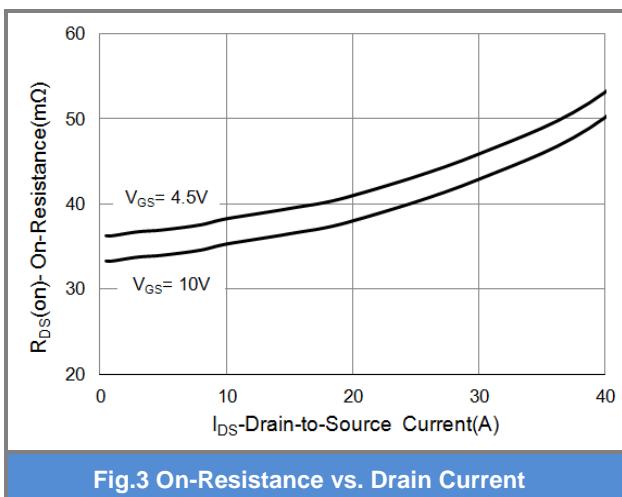
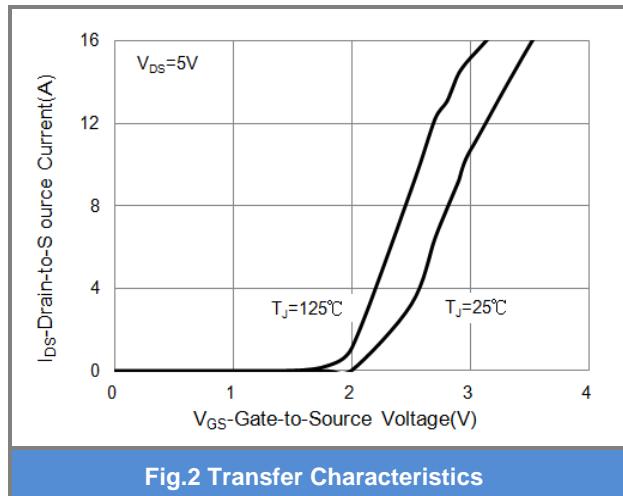
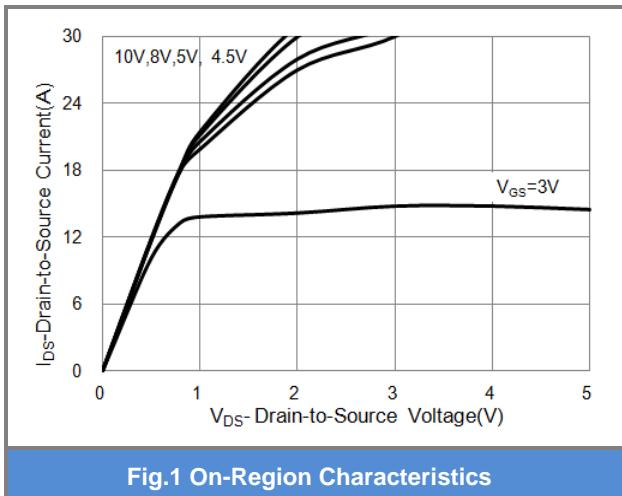
### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature  $T_J(MAX)=150^\circ C$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J = 25^\circ C$ .
5. The test condition is  $L=0.1mH, I_{AS}=18A, V_{DD}=25V, V_{GS}=10V$
6.  $R_{eJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
7. Guaranteed by design, not subject to production testing.



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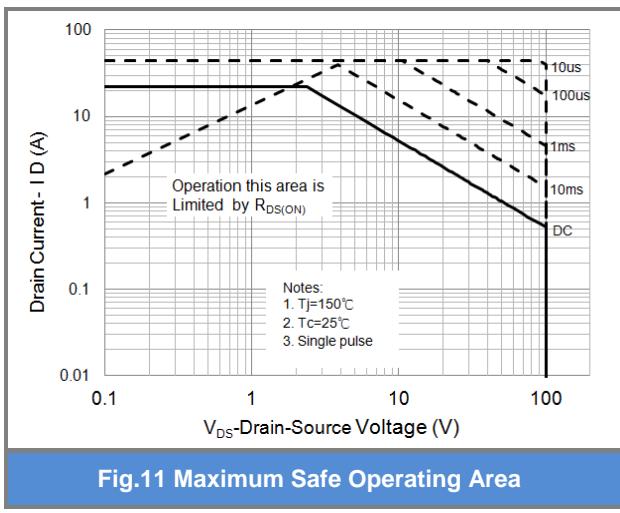
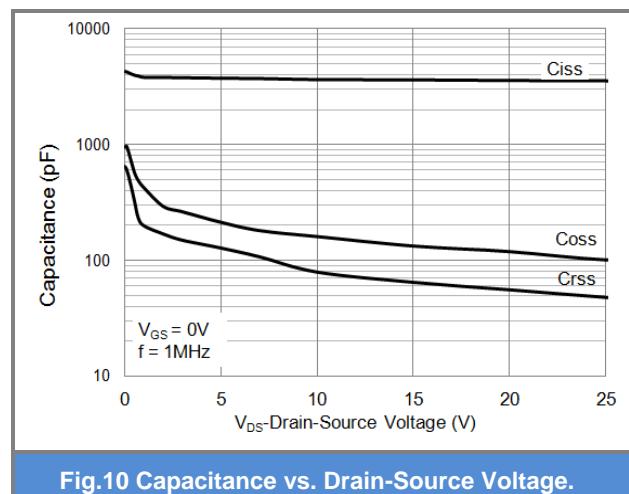
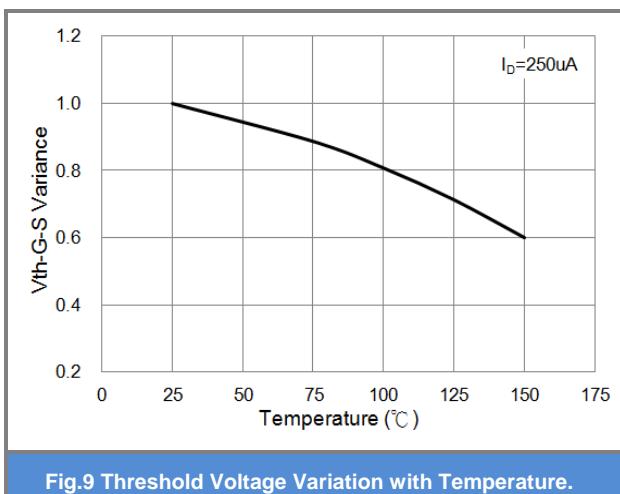
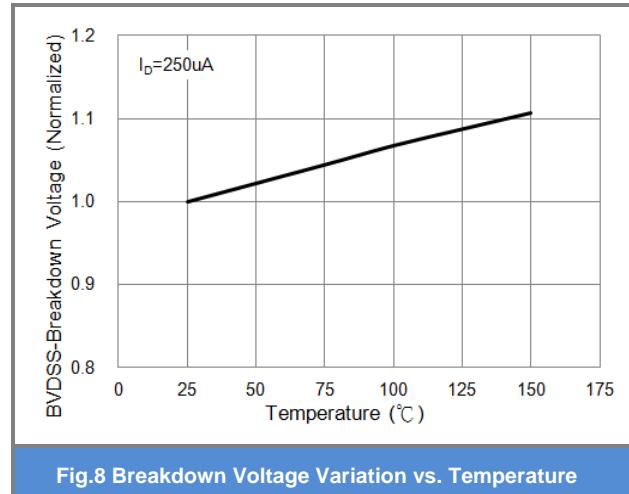
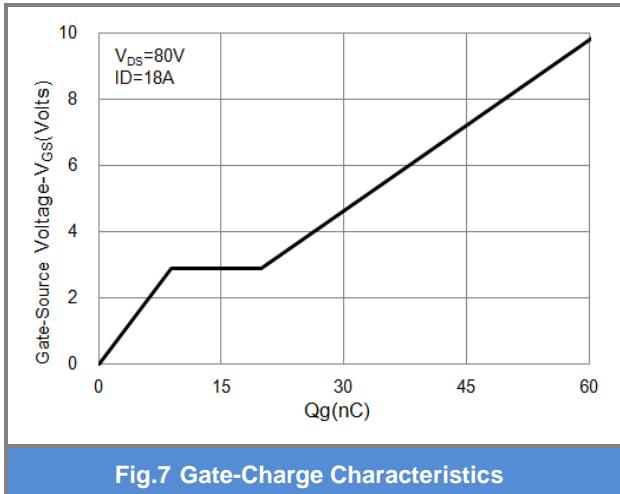
## TYPICAL CHARACTERISTIC CURVES





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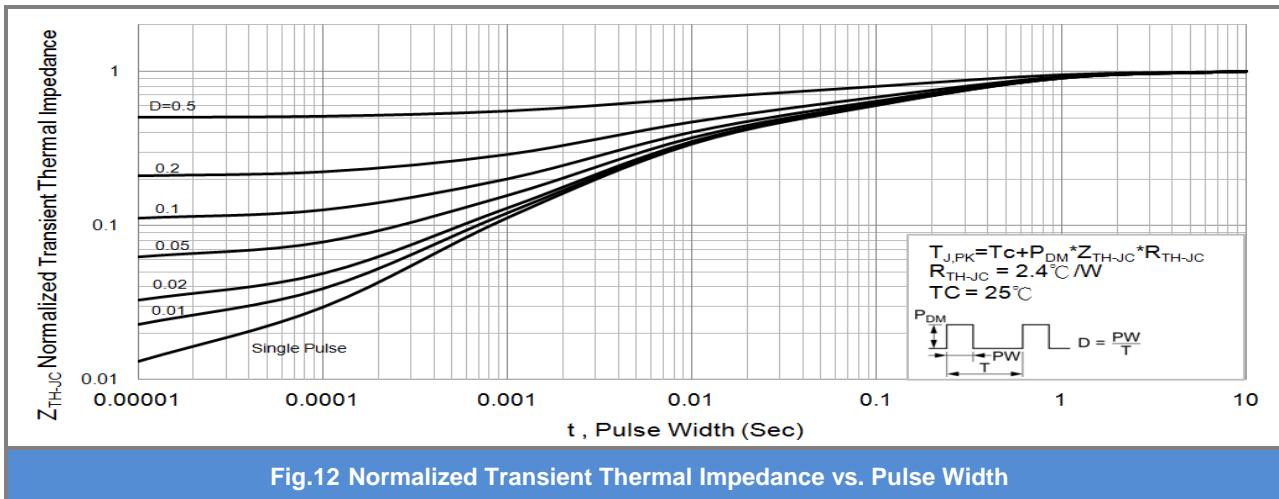
## TYPICAL CHARACTERISTIC CURVES





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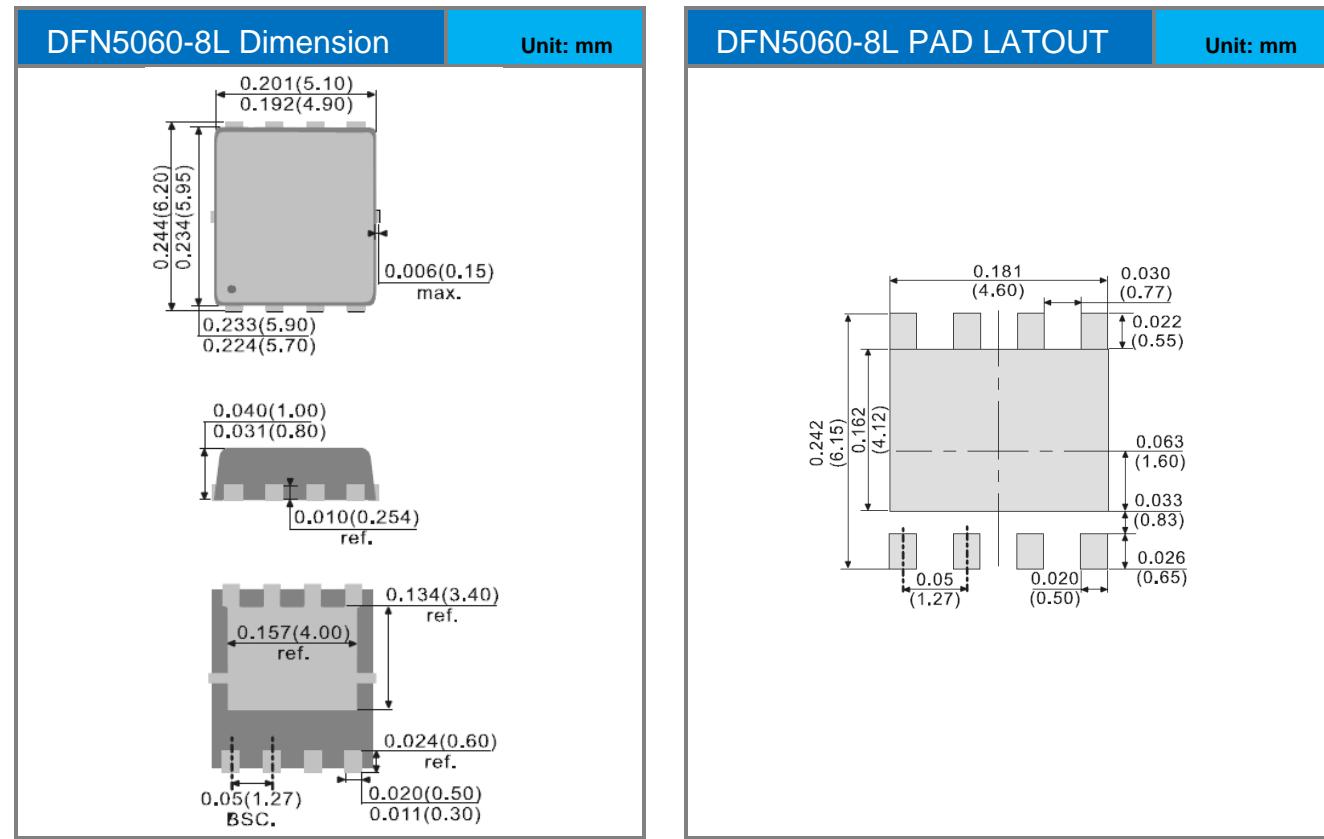


# PJQ5474A

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJQ5474A_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5474A	Halogen free

## Packaging Information & Mounting Pad Layout





## PJQ5474A

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